

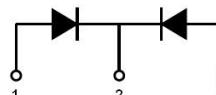
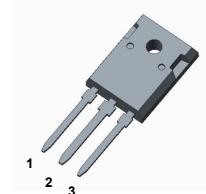
60A, 150V Schottky Barrier Diode

Description

The AKS6015DNH is a Schottky Barrier Diode and based on silicon extension process. It has very low switching losses and high ESD / surge current capability. Because of schottky barrier structure, the device suit for rectifier, free wheeling diode in high frequency and low voltage devices, like SMPS or PFC.

Features

- Low Forward Voltage Drop: $V_F=0.6V$ (typical @ $I_F=30A$)
- Reverse Voltage: $V_{RRM}=150V$
- Extremely Low Switching Losses
- High ESD and Surge Current Capability
- Low Reverse Leakage
- Standard TO-247 Package



1. Anode 2.Cathode 3.Anode

Applications

- Rectifier in SMPS
- Free Wheeling Diode in PFC
- High Frequency Devices

Absolute Maximum Ratings

per diode at $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter		Ratings	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage		150	V	
V_{RWM}	Working Peak Reverse Voltage		150	V	
V_R	DC Blocking Voltage		150	V	
$I_{F(AV)}$	Average Rectified Forward Current	per device at $T_C=125^\circ C$	60	A	
I_{FSM}	Non-repetitive Peak Surge Current		$t_p=10ms$, half sine wave	400	A
P_D	Power Dissipation		138	W	
T_J	Operating Junction Temperature Range		-60~+150	°C	
T_{STG}	Storage Temperature Range		-60~+175	°C	

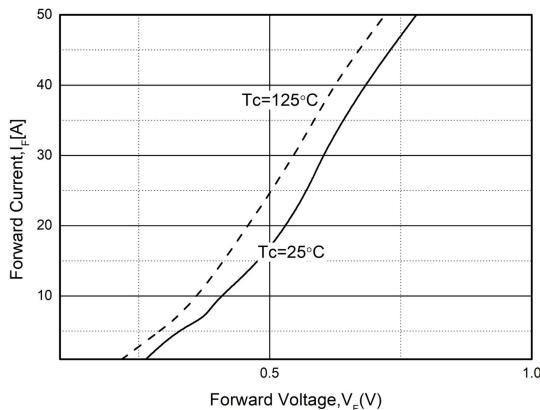
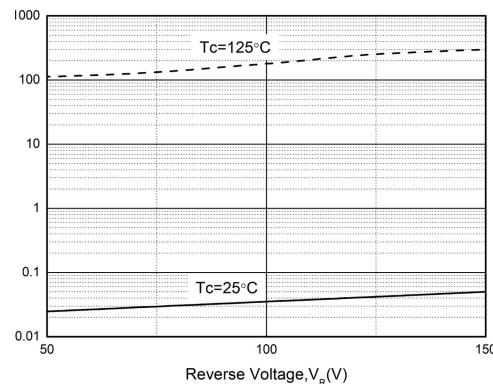
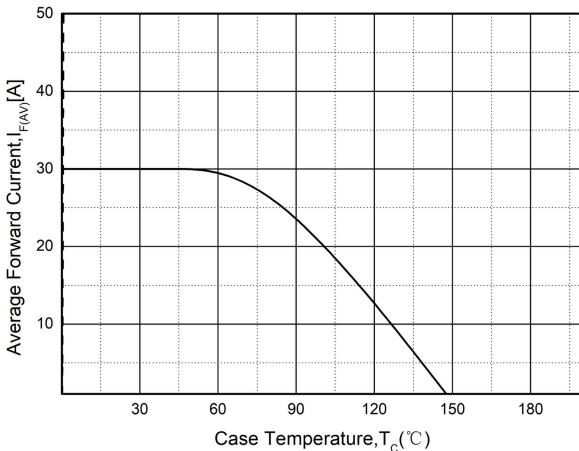
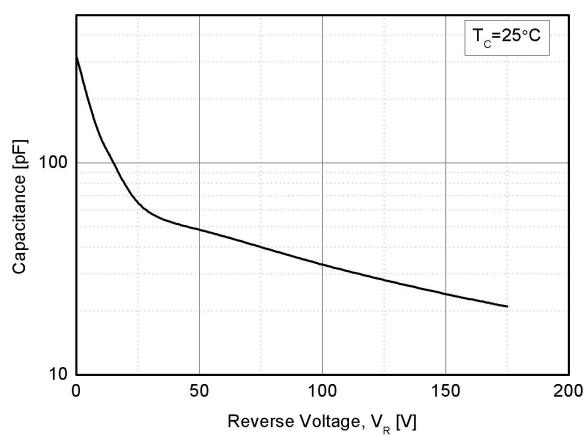
Thermal Characteristics

Symbol	Parameter	Ratings	Unit
$R_{th(J-C)}$	Thermal Resistance, Junction to case	0.9	°C/W

Electrical Characteristics per diode at $T_c=25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_F	Forward Voltage Drop	$I_F=30\text{A}$	-	0.6	0.8	V
		$I_F=30\text{A}, T_c=125\text{ }^\circ\text{C}$	-	0.55	-	V
I_R	Reverse Leakage Current	$V_R=150\text{V}$	-	-	100	uA
		$V_R=150\text{V}, T_c=125\text{ }^\circ\text{C}$	-	-	2.5	mA

Typical Performance Characteristics

 Fig. 1. Typical Characteristics: I_F vs. V_F

 Fig. 2. Typical Characteristics: I_R vs. V_R

 Fig. 3. Typical Characteristics: $I_{F(AV)}$ vs. T_c

 Fig. 4. Typical Characteristics: Capacitance vs. V_R


Package Dimensions**TO-247**

(Dimensions in Millimeters)

